

Citations for Ion : **Dy**

Pub. Year	Authors, Title, Journal Citation and Comments	Citation Numb
1964	Alexander, J. M. Gilat, J. Sisson, D. H. 'Neutron and Photon Emission from Dysprosium and Terbium Compound Nuclei: Range Distributions' <i>Phys. Rev. B, 136, 1289-97 (1964)</i> <i>Comment : R. 6-21 MeV Dy, Tb -> H2, D2, Al</i>	1964-Alex
1964	Gilat, J. Alexander, J. M. 'Stopping of Dysprosium Ions in Gases and Al' <i>Phys. Rev. B, 136, 1298-1305 (1964)</i> <i>Comment : R. 6-21 MeV Dy -> He, N2, Ne, Ar, Kr, Xe</i>	1964-Gila
1974	Grant, W. A. Williams, J. S. Dodds, D. 'Measurement of Projected and Lateral Range Parameters for Low Energy Heavy Ions in Silicon by Rutherford Backscattering' <i>Meyer, G. Linker and F. Kappeler (Ed.): Ion Beam Surface Layer Analysis, Plenum, N. Y., P. 235-44 (1974)</i> <i>Comment : R, dR, dR(Lateral). 10-80 keV Pb, 50-400 keV Bi, 40 keV Ar, Cu, Kr, Cd, Al, Dy, W -> Si</i>	1974-Gran
1975	Williams, J. S. Grant, W. A. 'High Resolution Rutherford Backscattering and Its Application to Ion Range and Ion Collectionrad' <i>Rad. Effects, 25, 55-56 (1975)</i> <i>Comment : R, dR. 20-80 keV Kr, Xe, Cs, Dy, Au, Pb, Bi -> Si, Al</i>	1975-Will
1976	Baragiola, R. A. Chivers, D. Dodds, D. Grant, W. A. Williams, J. S. 'Ranges in Silicon of Ions with Atomic Numbers $62 \leq Z1 \leq 66$ at 100 keV' <i>Phys. Letters A, 56, 371=73 (1976)</i> <i>Comment : R, dR. 100 keV 152Sm, 153Eu. 157Gd, 159Tb, 164Dy -> Si</i>	1976-Bara
1976	Grant, W. A. Dodds, D. Williams, J. S. Christodoulides, C. E. Baragiola, R. A. 'Heavy Ion Ranges in Silicon and Aluminum' <i>Ion Implantation in Semiconductors, Ed. by F. Chernow, J. A. Borders, D. K. Brice, 693-703 (1976)</i> <i>Comment : R. 0.01 < Epsilon < 0.8 Cr, Ni, Ga, As, Br, Mo, Cs, La, Nd, Dy, Ta, Pt, Au, Pb -> Si, Al</i>	1976-Gran
1976	Grant, W. A. Williams, J. S. Dodds, D. 'Measurement of the Lateral Spread of Heavy Ions Implanted into Silicon' <i>Rad. Effects, 29, 189-90 (1976)</i> <i>Comment : dR(Lateral). (10-40 keV) Cu, Cd, Xe, Dy, Kr, W, Pb, Bi -> Si</i>	1976-Gran3
1976	Varley, G. Willmott, J. C. Kearns, F. 'The Energy Losses of Heavy Ions' <i>Nucl. Inst. Methods, 135, 167-72 (1976)</i> <i>Comment : S. 70-250 MeV Nd -> Nd, Dy -> Dy, Er -> Er, 180-300 MeV Kr -> Nd, Dy, Er</i>	1976-Varl

Citations for Ion : **Dy**

Pub. Year	Authors, Title, Journal Citation and Comments	Citation Numb
1977	Christodoulides, C. E. Grant, W. A. Williams, J. S. 'Rutherford Backscattering Analysis of Ion-Implanted, Thermally Oxidized Silicon' <i>J. Electrochem. Soc., 124, 1651-1653 (1977)</i> <i>Comment : R. 20 keV Dy, Pb, Xe -> Si (With SiO2)</i>	1977-Chri
1978	Combasson, J. L. Farmery, B. W. McCulloch, D. Neilson, G. W. Thompson, M. W. 'Heavy Ion Ranges in Aluminum and Silicon' <i>Rad. Effects, 36, 149-156 (1978)</i> <i>Comment : R, dR. 20-250 keV Cs, La, Pr, Eu, Tb, Dy, Ho, Er, Lu, Hf, Pt, Au, Tl, Pb, Bi -> Al; Sm, Eu, Gd, Tb, Dy -> Si</i>	1978-Comb
